Electronic Supplementary information

Mixed valence Sn doped (CH₃NH₃)₃Bi₂Br₉ produced by mechanochemical synthesis

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Characterization

Powder X-ray diffraction (PXRD) patterns were measured on a Stoe STADI-P diffractometer (50 kV, 30 mA) using monochromated (Mo K α 1, 0.70930 Å) X-ray sources in transmission geometry with a STOE Dectris Mythen 1k detector. 2 θ values ranging from 2.0° to 40.1° in steps of 0.5° at 10.0 s/step.

X-ray photoelectron spectroscopy (XPS) data were collected on a Thermo Scientific K-alpha photoelectron spectrometer with a monochromatic Al K α radiation (photon energy of 1486.6 eV, 72 W 400 μ m X-ray spot size). CasaXPS software was used to process the XPS data with the charge correction based on the adventitious carbon C 1s at 284.8 eV. The Shirley background was applied for peak area measurements. Multiple analysis points were collected for each sample to calculate the homogeneity of each compound.

The Sn Auger parameter was calculated following the work of Felix *et al.* [REF 45 in main text]. We calculate $a_{Sn}^* = BE_{XPS} + KE_{XAES}$ using the Sn $3d_{3/2}$ coreline, and the Sn $M_4N_{4,5}N_{4,5}$ X-ray induced Auger line. Values are compared with Sn oxide and oxyhalide samples discussed in reference 45.

The UV-Vis optical spectra for microcrystals were conducted on a Shimadzu UV-2600 spectrometer with two external detectors in diffuse reflectance mode ($\lambda = 200-1400$ nm, slit width = 5 nm). A barium sulfate pellet was used as the reflecting reference. The Kubelka-Munk relationship equation: F(R) = $(1-R)^2/2R$ was applied to convert the reflectivity (R) into absorbance (A).

Table S1 Nominal and measured (XPS) percentage of Sn in $MA_3(Sn_xBi_{(1-x)})_2Br_9$ prepared bysimple room temperature doping and after 200 °C heating, calculated from XPS core-levelspectra.

Theoretical Sn concentration	Measured Sn concentration (XPS)	
	room temperature	after annealing
		200 °C
0%	0%	0%
1%	7.0%	3.0%
25%	31.1%	23.4%
30%	38.6%	36.0%
40%	31.0%	42.1%
50%	51.6%	47.8%
60%	60.6%	60.3%

$SnBr_2 + MA_3Bi_2Br_9$



 $SnBr_4 + MA_3Bi_2Br_9$

Figure S1 Colour change of the room temperature mechanochemical doping reaction of the yellow $MA_3Bi_2Br_9$ (top left), the mixture of white $SnBr_2$ powder and $MA_3Bi_2Br_9$ before grinding (top centre) and the final product after grinding (top right). Bottom row, the same procedure with $SnBr_4$ instead of $SnBr_2$ yields no colour change.



Figure S2 Powder XRD patterns of $MA_3(Sn_xBi_{(1-x)})_2Br_9$ after annealing at 200°C in air.

Table S2. Refined lattice parameters from $MA_3(Sn_xBi_{(1-x)})_2Br_9$ samples after annealing at200°C in air.

X	A / Å	C / Å	V / Å ³
0	8.2124(28)	10.0106(27)	584.70(12)
0.01	8.2144(19)	10.0130(27)	585.13(13)
0.25	8.2080(21)	10.0043(31)	583.71(11)
0.3	8.2140(18)	10.0047(26)	584.57(11)
0.4	8.2113(18)	10.0024(22)	584.06(19)
0.5	8.2106(18)	10.0038(27)	584.05(19)
0.6	8.2069(14)	9.9962(22)	583.08(10)



Figure S3. UV – vis absorption of $MA_3(Sn_xBi_{(1-x)})_2Br_9$ after annealing at 200°C in air. Inset, photograph of the samples with increasing x from left to right. Samples with x=0.3 retain the black colour even after annealing.



Figure S4. Survey XPS spectra of Sn:MA₃Bi₂Br₉ before (top) and after (bottom) 200°C air annealing.



Figure S5 Observation of Sn-doped $MA_3(Sn_xBi_{(1-x)})_2I_9$, where x = 0, 0.2, 0.3, 0.4, 0.5, prepared by mechanochemical reaction (a) at room temperature in air, (b) further heated in air at 200 °C for two hours after room temperature grinding.



Figure S6 Powder XRD patterns of room temperature Sn-doped $MA_3(Sn_xBi_{(1-x)})_2I_9$ where x = 0, 0.2, 0.3, 0.4, 0.5, compared with standard patterns of $MA_3Bi_2I_9$ and potential impurities including dopant SnI₂ and potential by-products of BiI₃ and BiOI.



Figure S7 UV-Vis absorption spectra of $MA_3(Sn_xBi_{(1-x)})_2I_9$ prepared by room temperature mechanochemical reaction, where x = 0, 0.2, 0.3, 0.4, 0.5.



Figure S8 (a) Energy profile diagram of Sn(II) to Sn(IV) IVCT mechanism. (b) Structure of MA₃Bi₂Br₉







Figure S10. Sn MNN X-ray excited Auger spectrum from Sn: MA3Bi2Br9